

CK-3.5

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# Saturable Absorption with CNT Coupled WGM and Fabrication of Er-doped Microresonator for On-chip Mode-locked Laser

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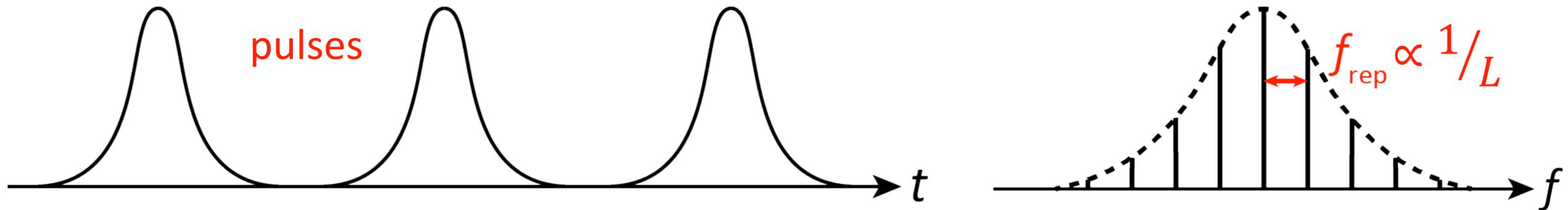
<sup>4</sup>PRESTO, Japan Science and Technology Agency, Kawaguchi, Saitama 332-0012, Japan

# Outline

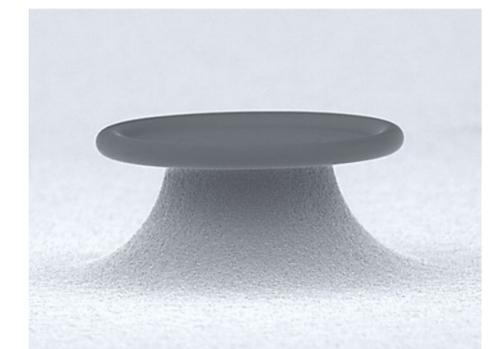
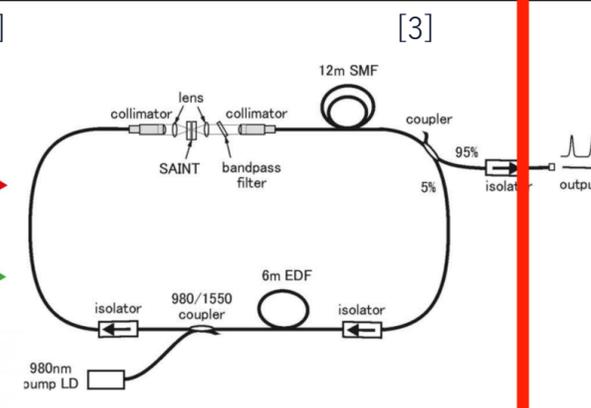
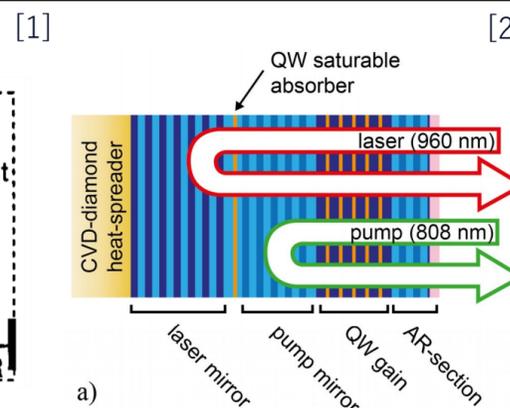
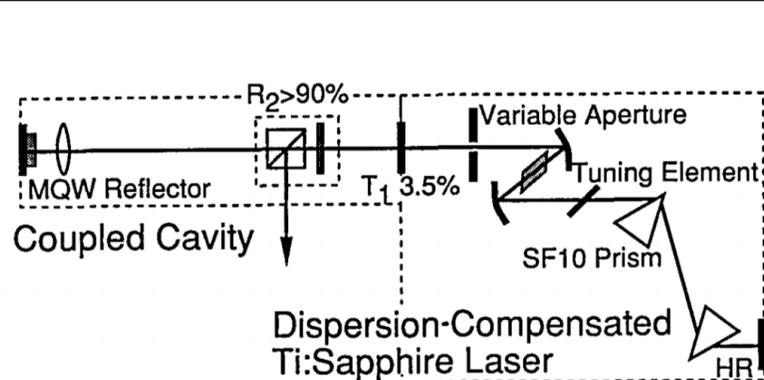
- Background & Objective
- Numerical model
- Saturable absorption of CNT
- Er-doped microresonator
- Summary



# Background: mode-locked laser



laser type	solid-state	semiconductor (MIXSEL)	fiber	microcavity
pulse width	~ 100 fs	~ 1 ps	~ 1 ps	~ 100 fs
repetition rate	~ 100 MHz	~ 10 GHz	~ 200 MHz	< 1000 GHz
wavelength	850 nm	650 ~ 2200 nm	1550 nm	1550 nm
footprint	×	○	△	◎

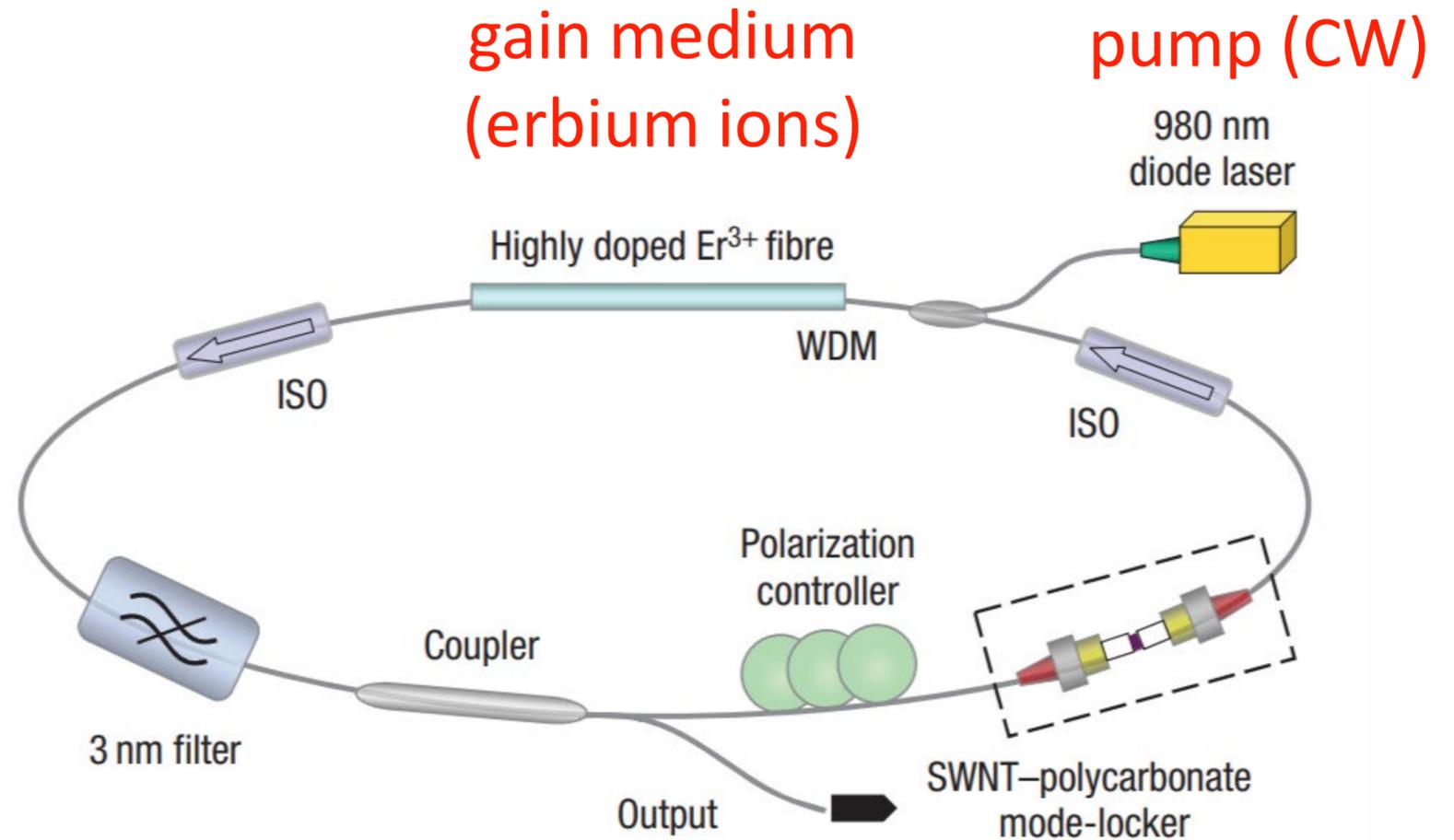


[1] U. Keller, *et al.*, *Opt. Lett.*, **16**, 13, 1022-1024 (1991) [2] M. Mangold, *et al.*, *Opt. Express* **22**, 6099-6107 (2014)

[3] Sze Y. Set, *IEEE J. Sel. Top. Quantum Electron.*, **10**, 1, 137-146 (2004)



# Background: mode-locked fiber ring system



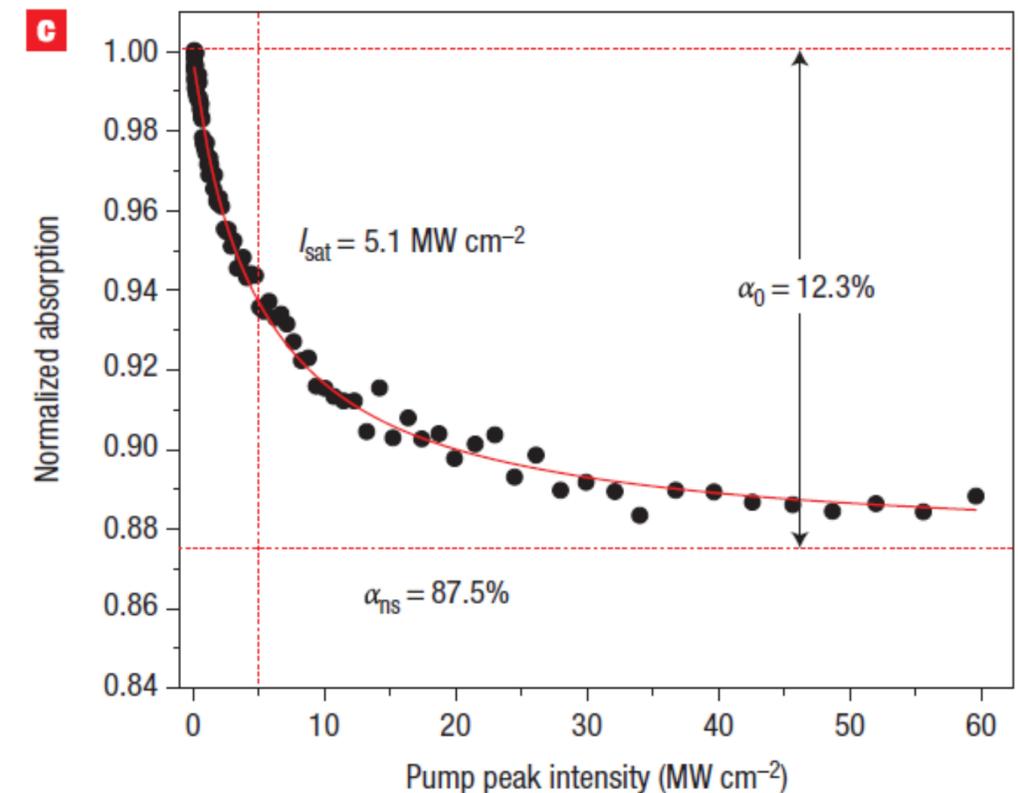
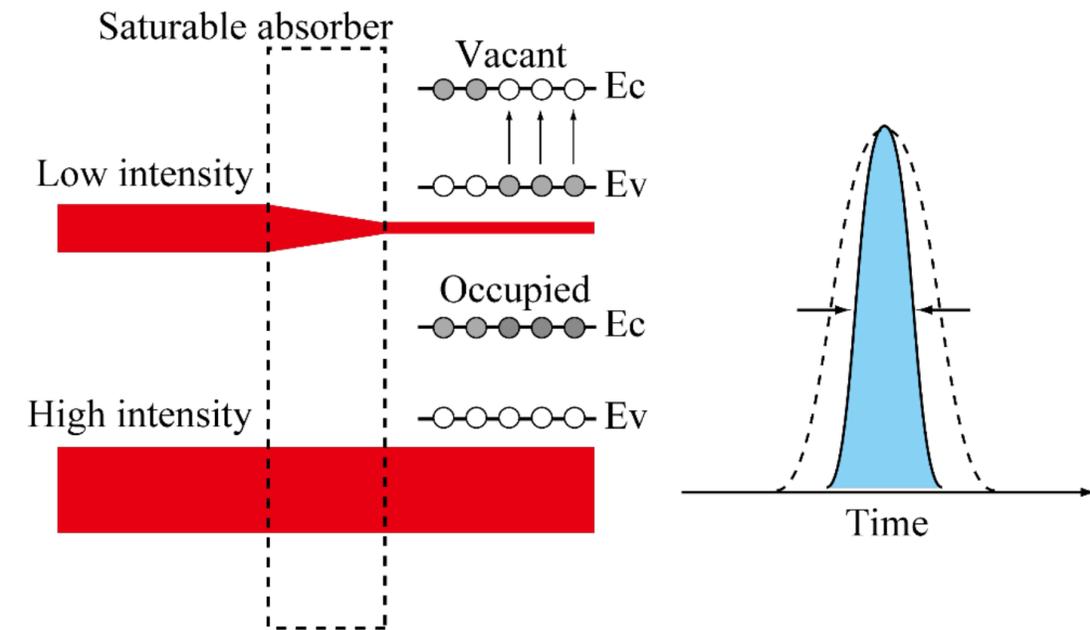
lasing at 1550 nm      saturable absorber (carbon nanotube)

Realizing this system with microcavity

*cavity length* : 13.3 m → 200 μm

*repetition rate* : 15 MHz → 1000 GHz

## Saturable absorption

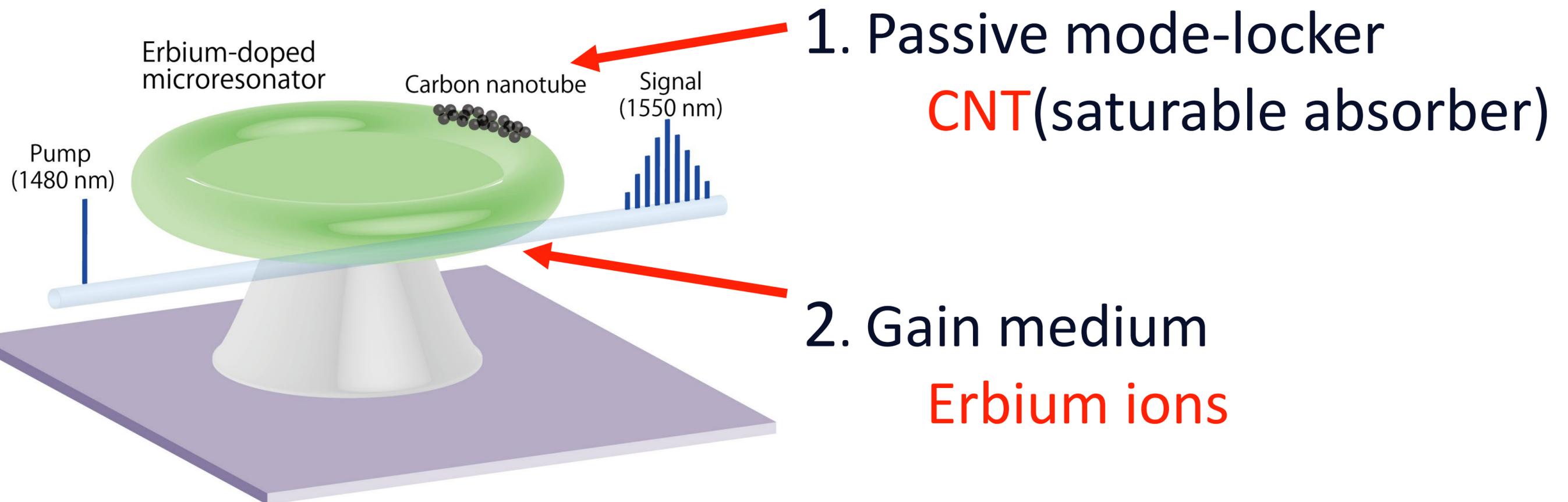


F. Wang, *et al.*, Nat. Nanotechnol., 3, 738-743 (2008)

# Objective:

## Mode-locked laser with microresonator

- high repetition rate ( $> \text{GHz}$ )
- small footprint
- on-chip integrability

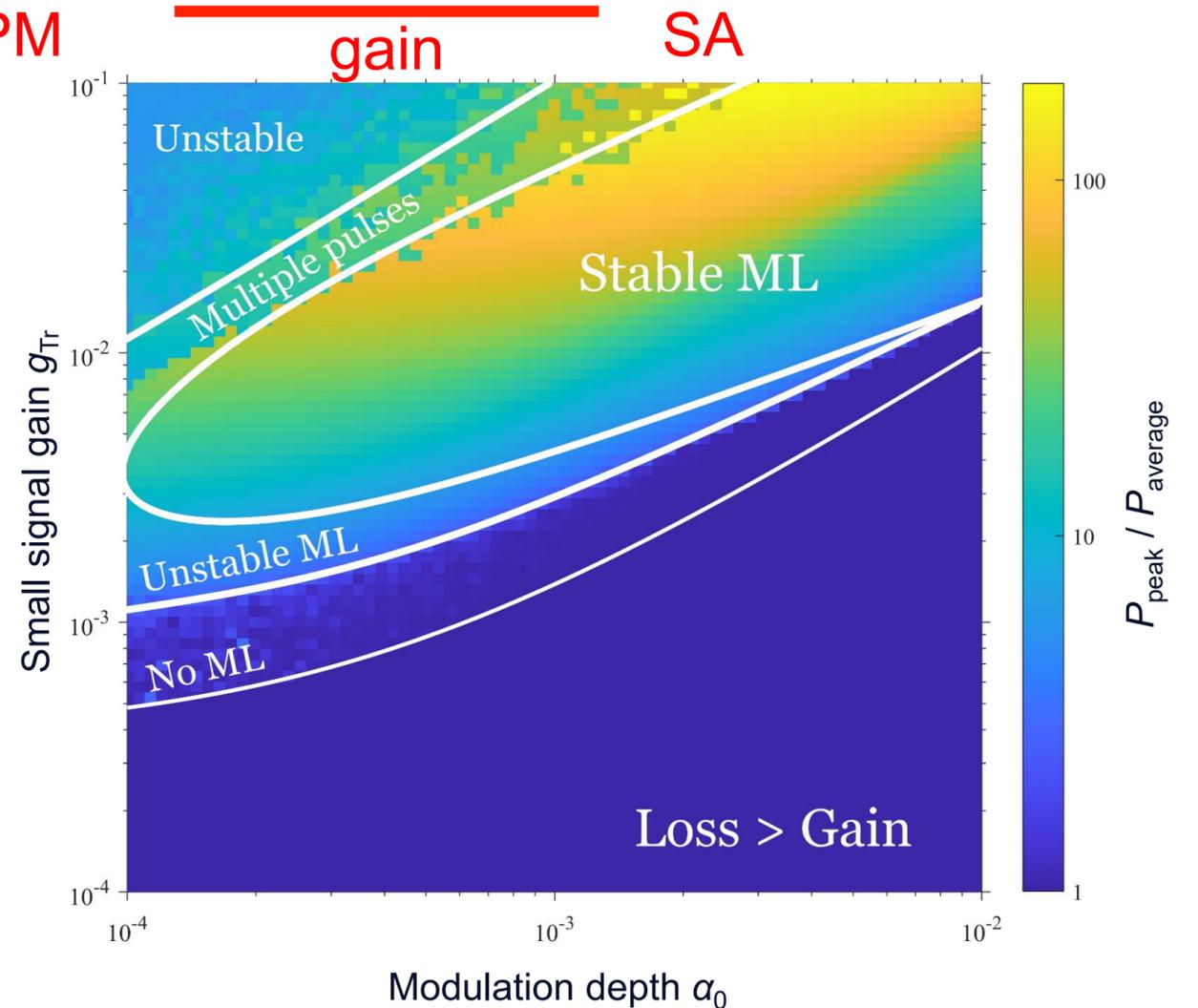
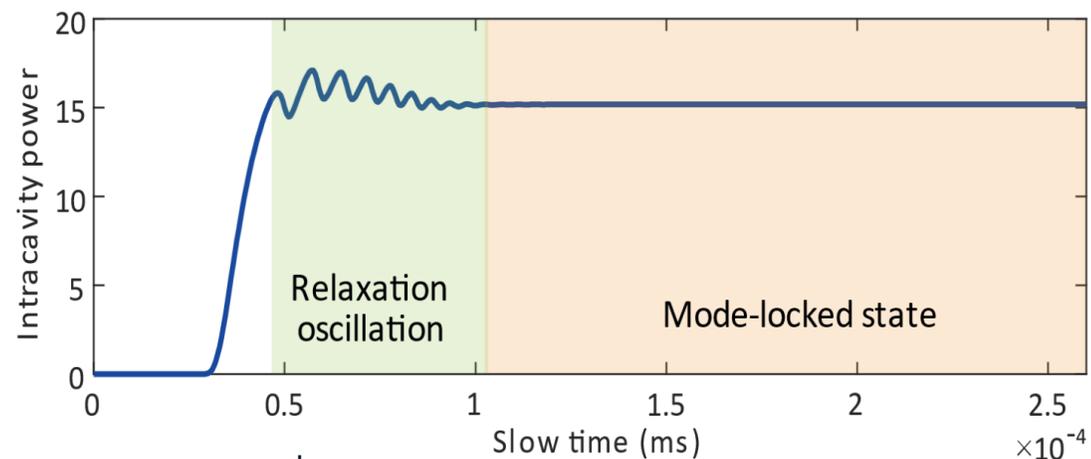
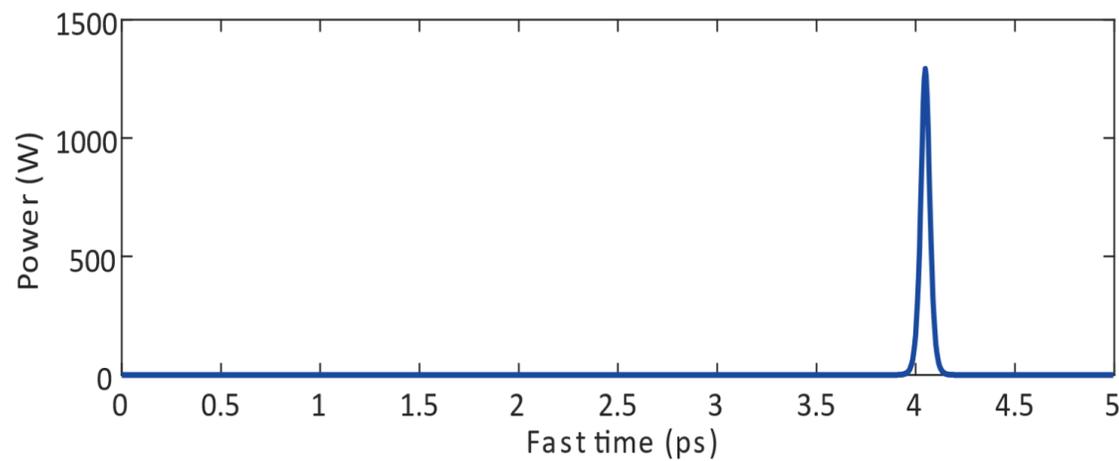
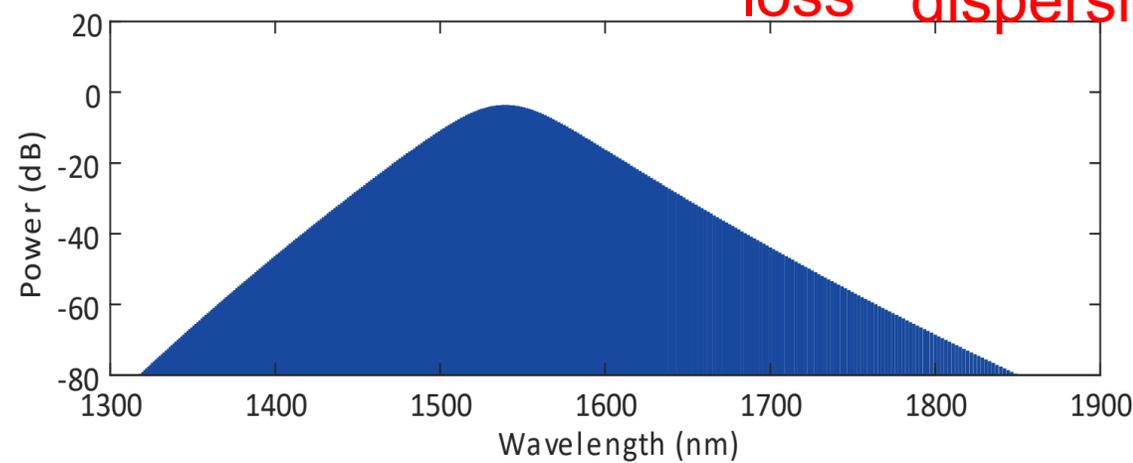




# Numerical model

Model: Nonlinear Schrödinger equation

$$t_R \frac{\partial E(t, \tau)}{\partial t} = \left[ \underbrace{-\frac{\alpha_{\text{tot}}}{2}}_{\text{loss}} - \underbrace{\frac{iL}{2} \beta_2 \frac{\partial^2}{\partial \tau^2}}_{\text{dispersion}} + \underbrace{iL\gamma |E|^2}_{\text{SPM}} + \underbrace{g(t)}_{\text{gain}} + \underbrace{\frac{g(t)}{\Omega_g^2} \frac{\partial^2}{\partial \tau^2}}_{\text{SA}} - q(t, \tau) \right] E$$



FSR = 200 GHz

$Q = 1 \times 10^7$

$\beta_2 = -10 \text{ ps}^2/\text{km}$

$g_0 = 0.01$

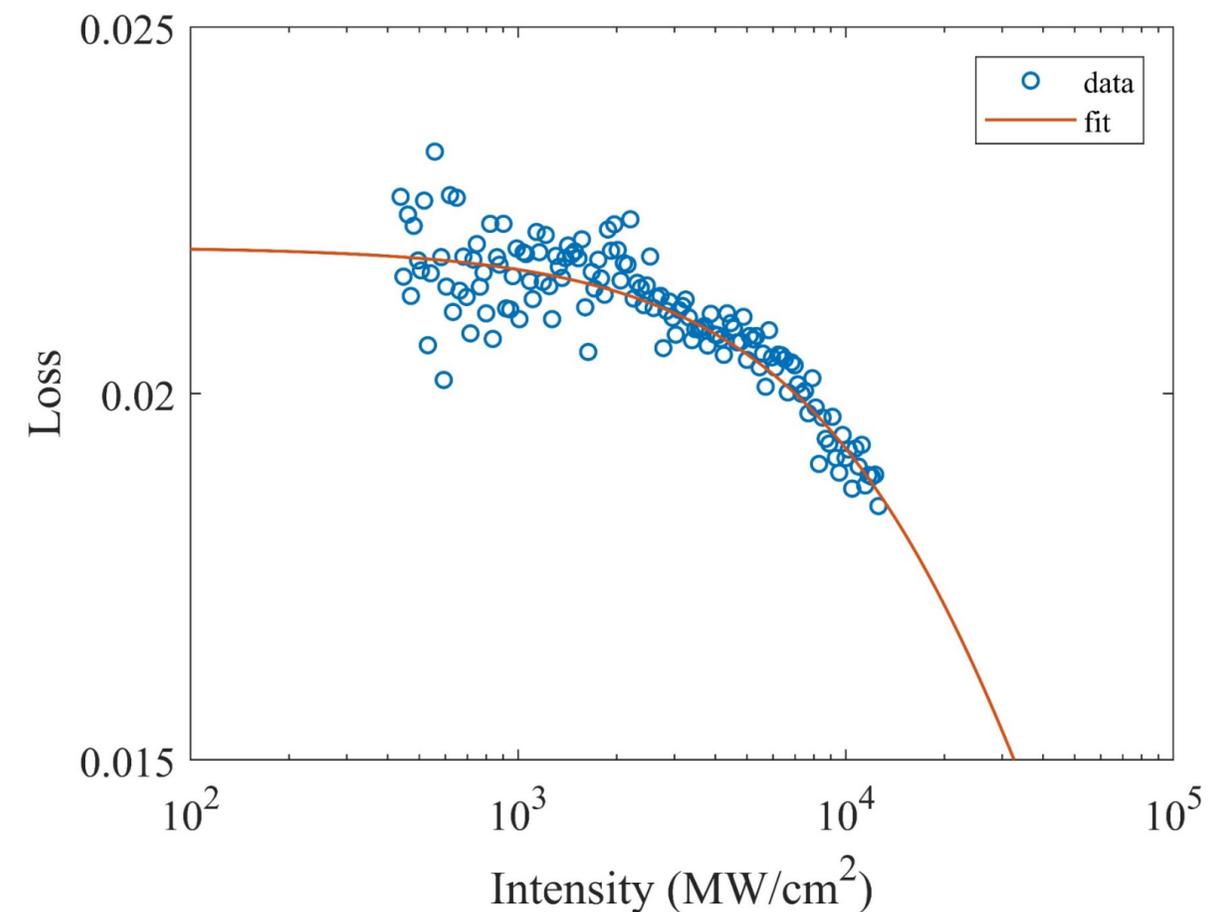
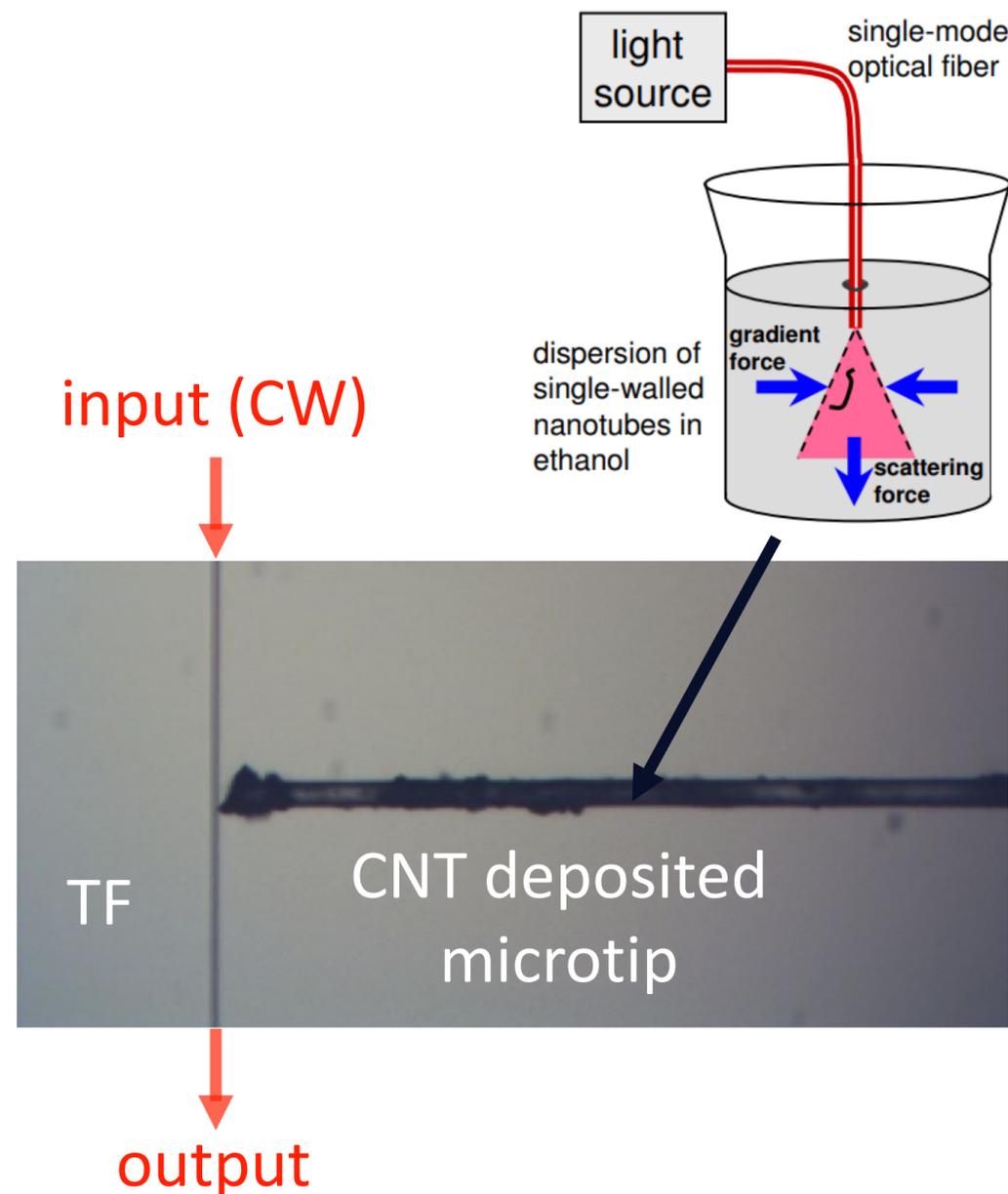
$q_0 = 0.049$



# Saturable absorption of CNT

## Optical deposition on fiber microtip

J. W. Nicholson, *et al.*, *Opt. Express*, **15**, 15, 9176-9183 (2007)

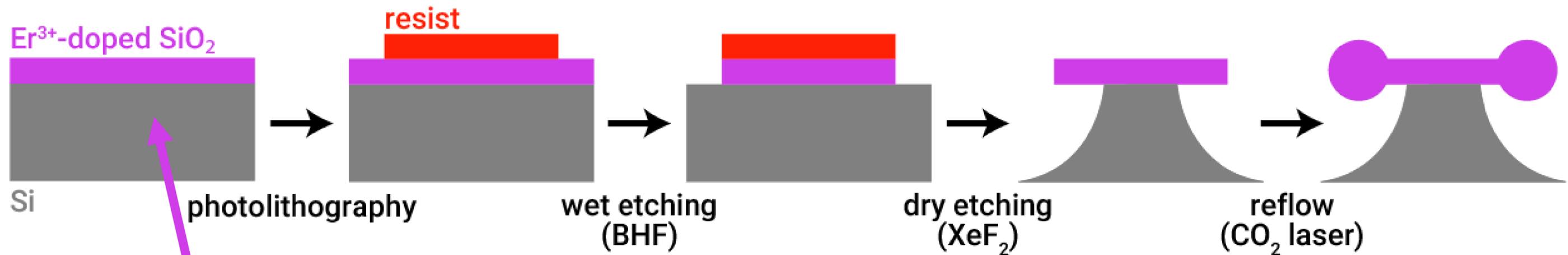


- By using optical deposited fiber tip, saturable absorption was observed
- By changing the gap distance between microtip and tapered fiber, the absorption can be controlled.

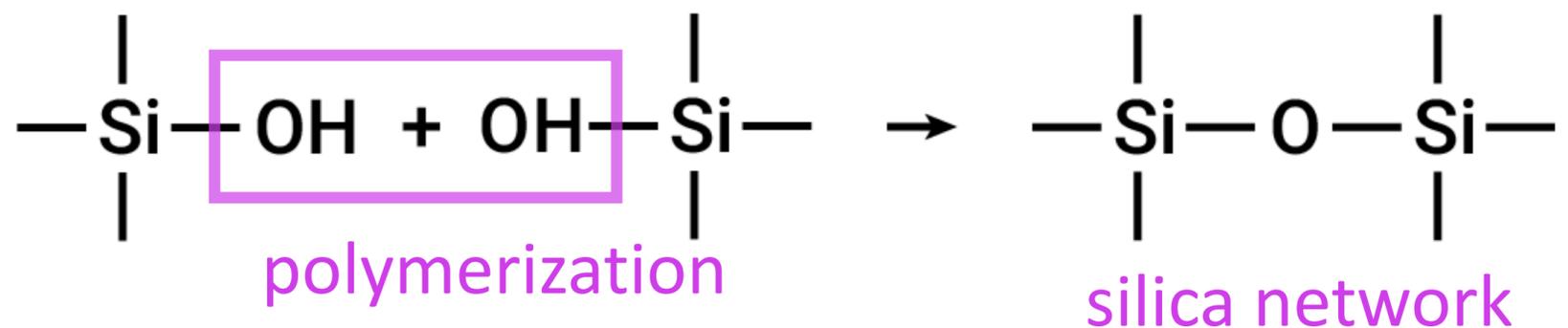
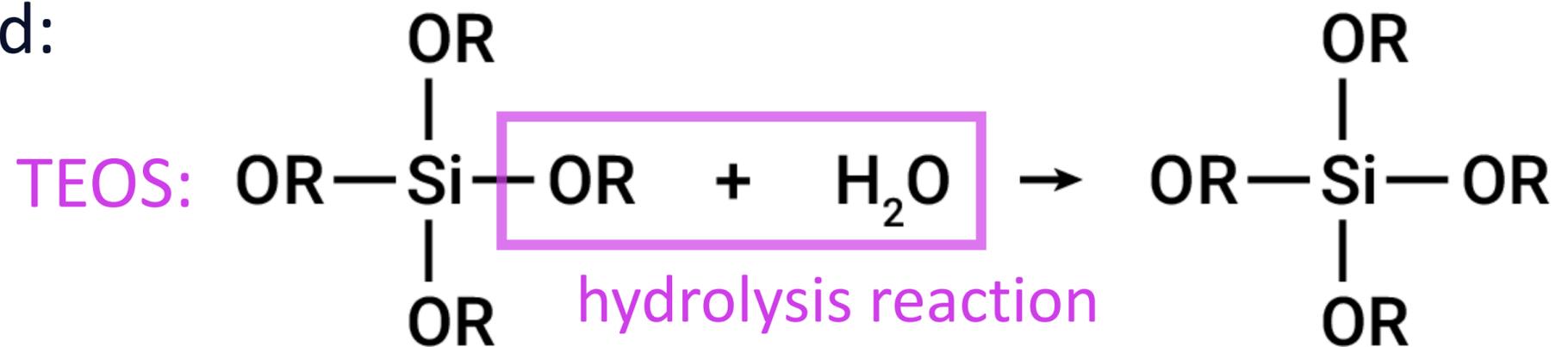


# Er-doped microresonator: Process flow

Fabrication flow of microtoroid by sol-gel method (cross-section).

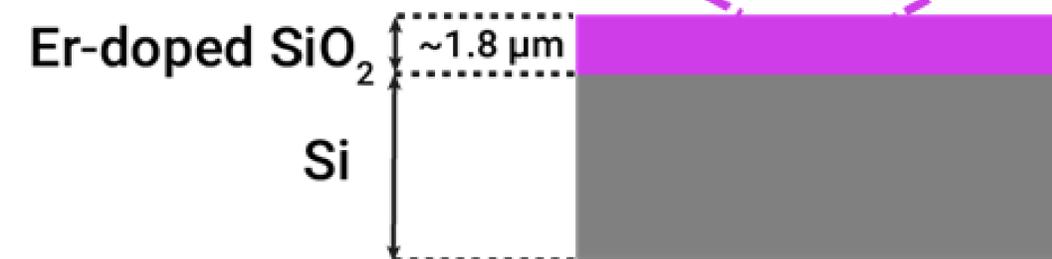
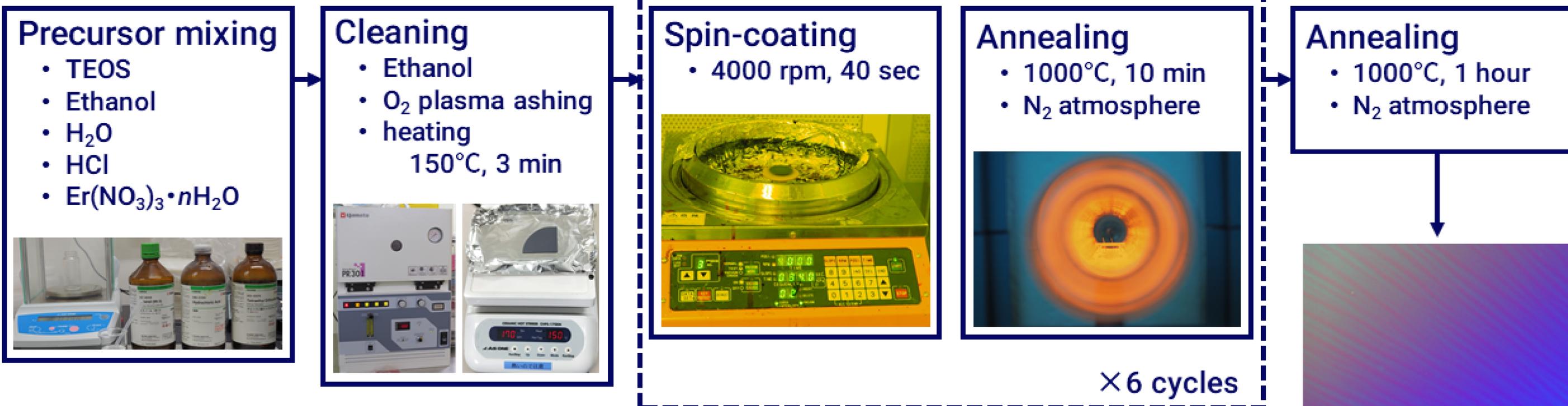
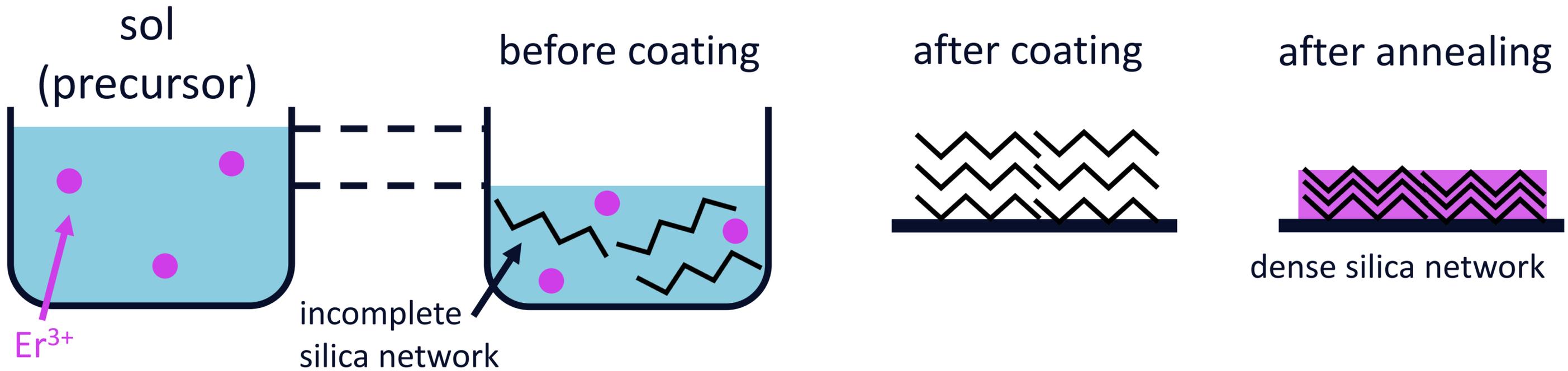


sol-gel method:





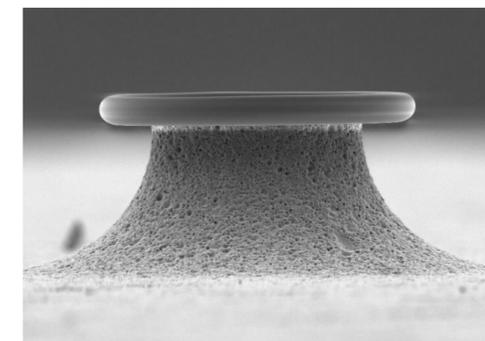
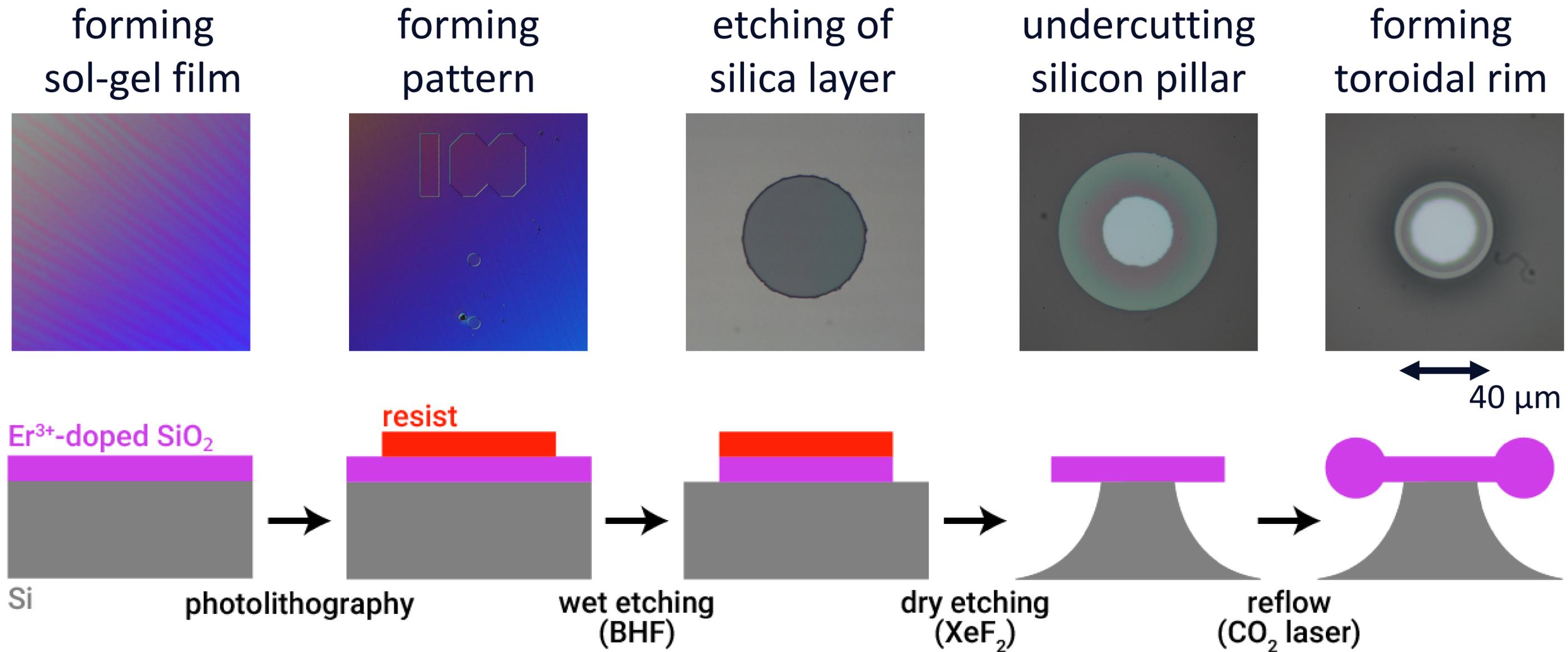
# Er-doped microresonator: Process flow





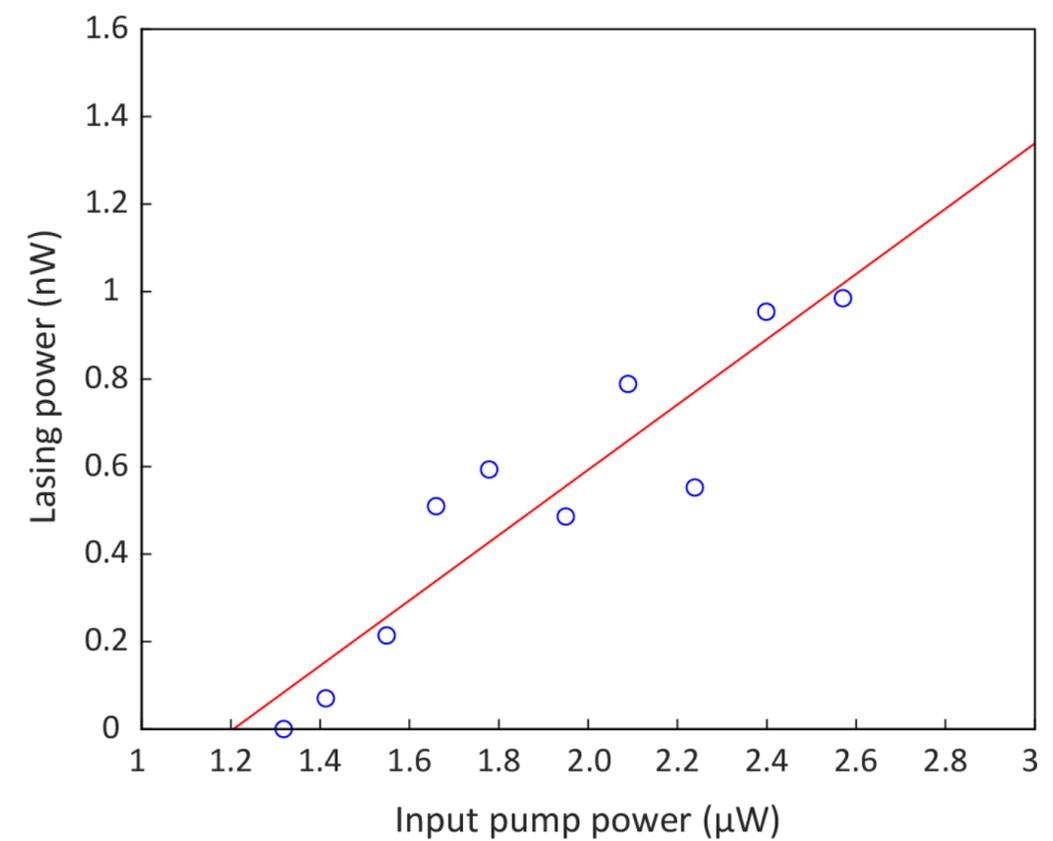
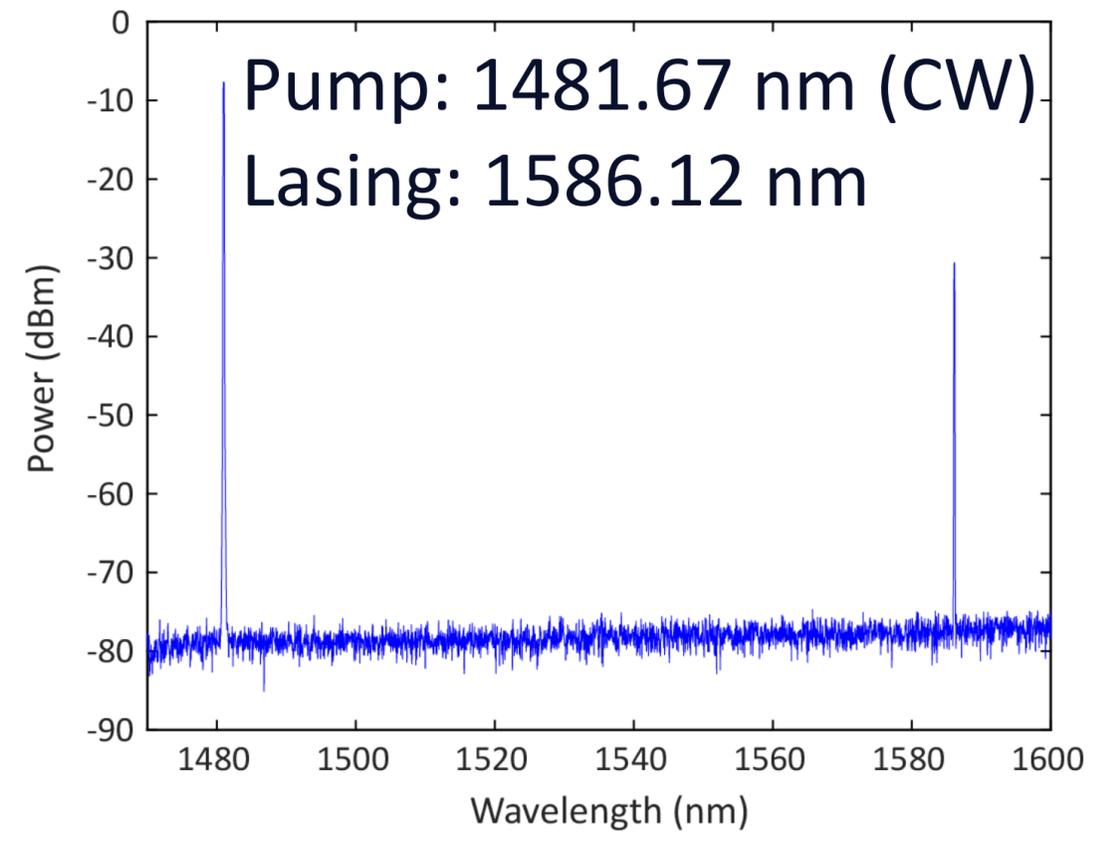
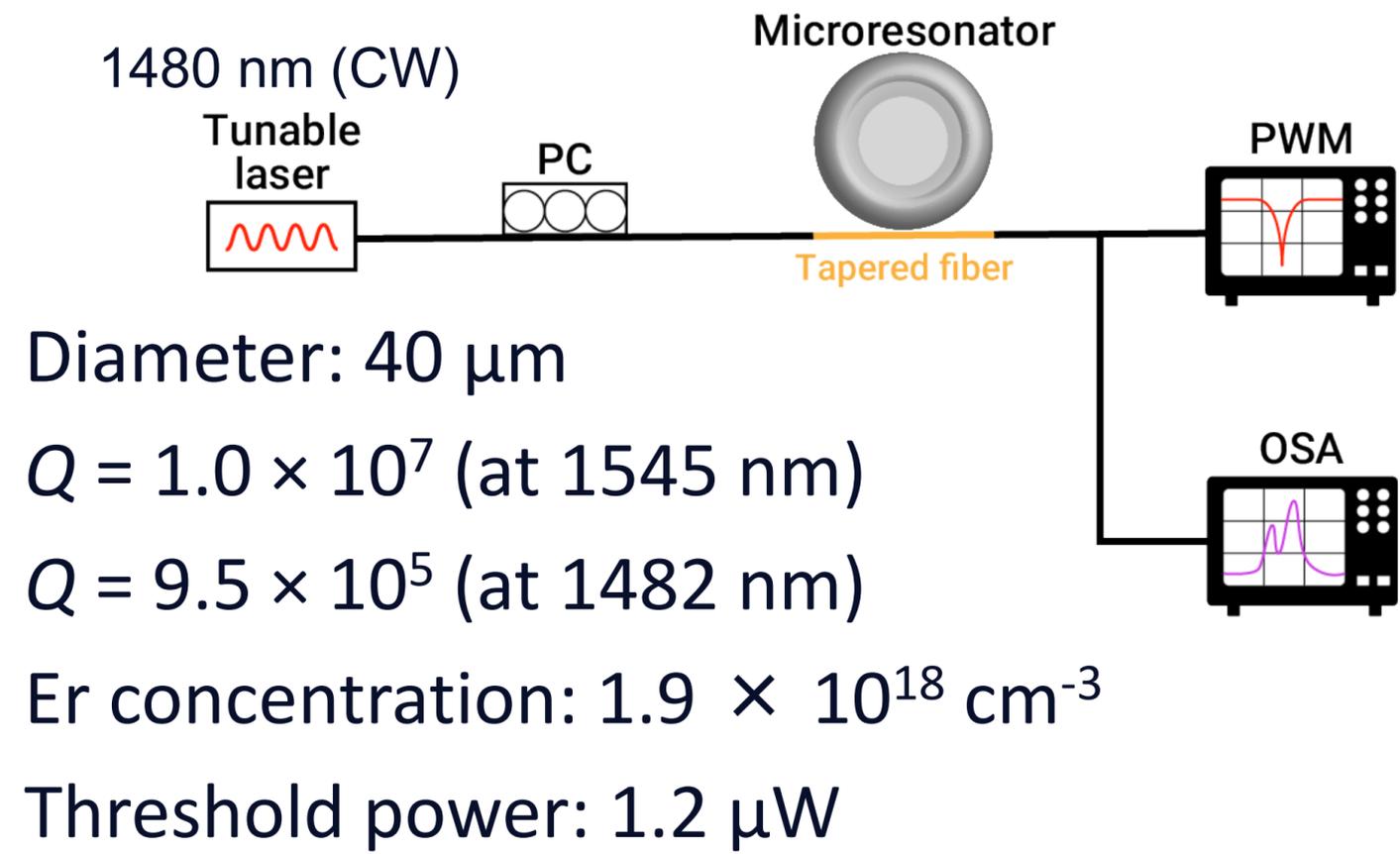
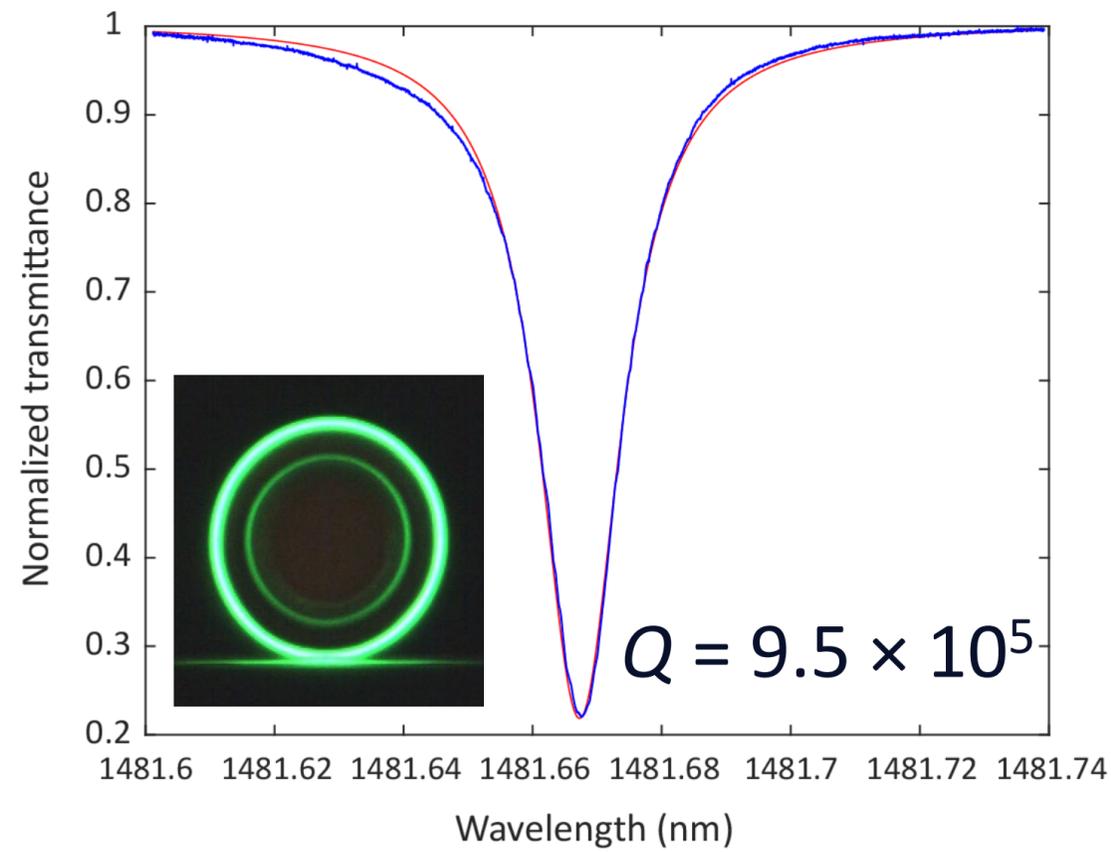
# Er-doped microresonator: Fabrication result

The thickness of sol-gel film is  $\sim 1.8 \mu\text{m}$  with 6 layers ( $\sim 300 \text{ nm/layer}$ ).





# Er-doped microresonator: Measurement





# Summary

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## Objective:

On-chip mode-locked laser with CNT and Er-doped microresonator

## Achievement:

- Saturable absorption of CNT
  - SA is obtained by using microtip
- Er-doped microresonator
  - Fabrication of Er-doped microtoroid
  - Lasing at  $\sim 1580$  nm

## Future plan:

- Measuring gain ( $g_0$ ) of Er-doped microtoroid
- Integration of CNT and Er-doped microtoroid

# Thank you.

## Acknowledgement:

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